

Twin 6-pack

SKiiP 24ACC12T4V1

Features*

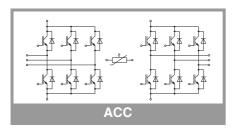
- Trench 4 IGBTs
- Robust and soft switching freewheeling diodes in CAL technology
- Highly reliable spring contacts for electrical connections
- UL recognized: File no. E63532

Typical Applications

• 4Q inverters

Remarks

- Max. case temperature limited to T_C=125°C
- Product reliability results valid for T_j≤150°C (recommended T_{j,op}=-40...+150°C)
- Terminal distances sufficient for basic insulation in 3-phase 480VAC TN systems
- DC-link voltage V_{DC}≤800V
- Temperature sensor: no basic insulation to main circuit, signal processing with reference to –DC potential
- Please refer to MiniSKiiP "Technical Explanations" and "Mounting Instructions" for further information
- Inverter IGBT=T1-T12
- Inverse Diode=D1-D12



| Absolute | e Maximum Ratings | | | |
|------------------------------|---|--|---------|------|
| Symbol | Conditions | | Values | Unit |
| IGBT 1 - | | | | |
| V _{CES} | 1 | | | V |
| Ic | λ _{paste} =0.8 W/(mK) | T _s = 25 °C | | Α |
| | T _j = 175 °C | T _s = 70 °C | | Α |
| I _C | λ _{paste} =2.5 W/(mK) | | | Α |
| | | T _s = 70 °C | | Α |
| I _{Cnom} | | <u> </u> | | Α |
| I _{CRM} | | | | Α |
| V _{GES} | | | | V |
| | | | | |
| t _{psc} | V _{GE} ≤ V | | n.c. | μs |
| т. | V _{CES} ≤ V | | | °C |
| T _j IGBT 7 - ' | 12 | | | |
| | T _i = 25 °C | | 1000 | V |
| V _{CES} | | T _s = 25 °C | 1200 | |
| Ic | λ_{paste} =0.8 W/(mK) T _i = 175 °C | $T_s = 25^{\circ} \text{C}$ $T_s = 70^{\circ} \text{C}$ | 38 | A |
| I. | , | $T_s = 70^{\circ} \text{C}$ $T_s = 25^{\circ} \text{C}$ | 42 | A |
| Ic | λ_{paste} =2.5 W/(mK) T _i = 175 °C | $T_s = 70 ^{\circ}\text{C}$ | 35 | A |
| I_ | 1,1-170-0 | 15-70 0 | 25 | A |
| I _{Cnom} | | | 75 | A |
| V _{GES} | | | -20 20 | V |
| V GES | V _{CC} = 800 V | | -20 20 | V |
| t _{psc} | V _{GE} ≤ 15 V V _{CES} ≤ 1200 V | T _j = 150 °C | 10 | μs |
| T _j | | | -40 175 | °C |
| Diode 1 - | . 6 | | | |
| V _{RRM} | | | | V |
| I _F | λ _{paste} =0.8 W/(mK) | T _s = 25 °C | | Α |
| | | T _s = 70 °C | | Α |
| l _F | λ _{paste} =2.5 W/(mK) | T _s = 25 °C | | Α |
| | | T _s = 70 °C | | Α |
| I _{FRM} | | | | Α |
| I _{FSM} | , , | | | Α |
| T_j | | | 175 | °C |
| Diode 7 - | 12 | | | |
| V_{RRM} | T _j = 25 °C | | 1200 | V |
| I _F | λ _{paste} =0.8 W/(mK) | T _s = 25 °C | 31 | Α |
| | T _j = 175 °C | T _s = 70 °C | 25 | Α |
| I _F | λ _{paste} =2.5 W/(mK) | T _s = 25 °C | 34 | Α |
| | T _j = 175 °C | T _s = 70 °C | 27 | Α |
| I _{FRM} | | | 50 | Α |
| I _{FSM} | 10 ms, sin 180°, T _j | = 150 °C | 100 | Α |
| Tj | | | -40 175 | °C |
| Module | | | | |
| I _{t(RMS)} | 20 A per spring | | 40 | А |
| T _{stg} | module without TIM | 1 | -40 125 | °C |
| | <u> </u> | min | | |



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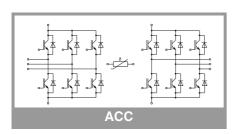
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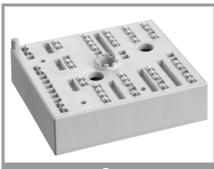
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| Characte | ristics | | | | | |
|-----------------------------------|---|---|-------|------|------|----------|
| Symbol | Conditions | | min. | typ. | max. | Unit |
| IGBT 1 - 6 |) } | | | | | |
| V _{CE(sat)} | | | | | | V |
| OL(out) | | | | | | V |
| | | | | | | ļ - |
| V _{CE0} | chiplevel | | | | | V |
| | | | | | | V |
| r _{CE} | | | | | | mΩ |
| V | | | | | | mΩ |
| V _{GE(th)} | , | | | | 0.2 | |
| I _{CES} | | | | | 0.3 | mA mA |
| C _{ies} | | | | | | nF |
| C _{oes} | | | | | | nF |
| C _{res} | | | | | | nF |
| Q _G | | | | | | nC |
| R _{Gint} | | | | 0 | | Ω |
| t _{d(on)} | | | | | | ns |
| t _r | | | | | | ns |
| E _{on} | - | | | | | mJ |
| t _{d(off)} | | | | | | ns |
| t _f | | | | | | ns |
| • | | | | | | |
| E _{off} | $V_{GE} = +15/-15 \text{ V}$ | | | | | mJ |
| R _{th(j-s)} | per IGBT, λ _{paste} =0. | 8 W/(mK) | | | | K/W |
| R _{th(j-s)} | per IGBT, λ_{paste} =2. | | | | | K/W |
| IGBT 7 - 1 | | 3 TT/(IIII T) | | | | 1077 |
| V _{CE(sat)} | I _C = 25 A | T _i = 25 °C | | 1.85 | 2.10 | V |
| V CE(sat) | V _{GE} = 15 V | - | | | | |
| | chiplevel | T _j = 150 °C | | 2.25 | 2.45 | V |
| V_{CE0} | chiplevel | T _j = 25 °C | | 0.80 | 0.90 | V |
| | | T _j = 150 °C | | 0.70 | 0.80 | V |
| r _{CE} | V _{GE} = 15 V | T _j = 25 °C | | 42 | 48 | mΩ |
| | chiplevel | T _j = 150 °C | | 62 | 66 | mΩ |
| V _{GE(th)} | $V_{GE} = V_{CE} V, I_C = 1$ | | 5.3 | 5.8 | 6.3 | V |
| I _{CES} | $V_{GE} = 0 V$ | T _j = 25 °C | | | 1 | mA |
| | V _{CE} = 1200 V | C 4 NALL | | - | | mA |
| C _{ies} | V _{CE} = 25 V | f = 1 MHz | | 1.45 | | nF |
| Coes | $V_{GE} = 0 V$ | f = 1 MHz | | 0.12 | | nF |
| Cres | V 0V . 15 V | f = 1 MHz | | 0.05 | | nF |
| Q _G | V _{GE} = -8 V+ 15 V | | | 142 | | nC |
| R _{Gint} | $T_j = 25 ^{\circ}\text{C}$ $V_{CC} = 600 ^{\circ}\text{V}$ | T _i = 150 °C | | 0 | | Ω |
| t _{d(on)} | I _C = 25 A | T _i = 150 °C | | 39 | | ns |
| t _r E _{on} | $R_{G \text{ on}} = 27 \Omega$ | $T_i = 150 \text{ C}$ $T_i = 150 \text{ °C}$ | | 3.2 | | ns mJ |
| | $R_{G \text{ off}} = 27 \Omega$ | $T_j = 150 \text{ C}$ $T_j = 150 \text{ °C}$ | | 333 | | |
| t _{d(off)} | $di/dt_{on} = 780 \text{ A/}\mu\text{s}$ $di/dt_{off} = 360 \text{ A/}\mu\text{s}$ | $T_j = 150 \text{ °C}$ | | 91 | | ns ns |
| *1 | $dv/dt = 3400 V/\mu s$ | ., - 100 0 | | J1 | | 113 |
| E_{off} | $V_{GE} = +15/-15 \text{ V}$ | T _j = 150 °C | | 3 | | mJ |
| - | L _s = 21 nH | | 14000 | | | |
| R _{th(j-s)} | per IGBT, λ _{paste} =0. | | | 1.13 | | K/W |
| $R_{th(j-s)}$ | per IGBT, λ _{paste} =2. | o vv/(mĸ) | | 0.94 | | K/W |



MiniSKiiP® 2

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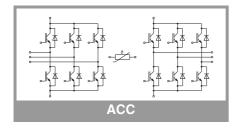
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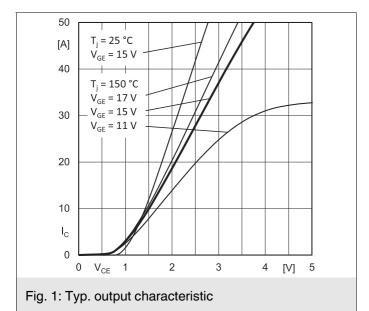
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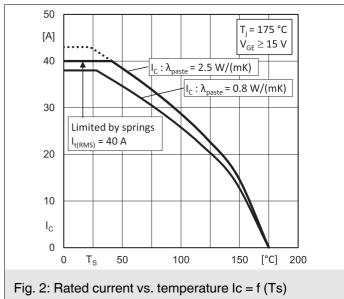
Remarks

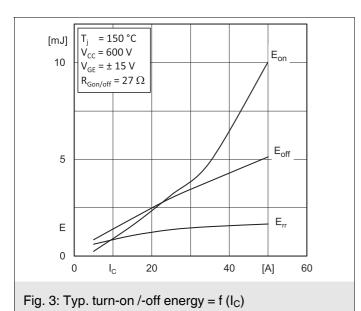
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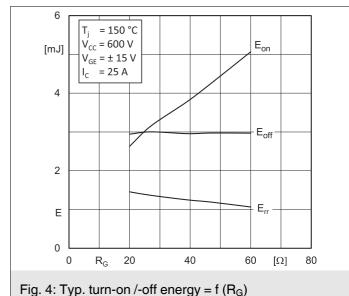
| Characte | ristics | | | | | |
|----------------------|--|--|--------------|--------|------|------|
| Symbol | Conditions | | min. | typ. | max. | Unit |
| Diode 1 - | 6 | | | | | |
| $V_F = V_{EC}$ | I _F = 25 A | T _j = 25 °C | | | | V |
| $V_{GE} = 0 V$ | | | | | | V |
| V _{F0} | ahinlayal | T _j = 25 °C | | | | V |
| | chiplevel | | | | | V |
| r _F | chiplevel | T _j = 25 °C | | 0.00 | 0.00 | mΩ |
| | Chipiever | | | 0.00 | 0.00 | mΩ |
| I _{RRM} | | T _j = 150 °C | | t.b.d. | | Α |
| Q_{rr} | V _{GE} = -15 V | T _j = 150 °C | | t.b.d. | | μC |
| E _{rr} | VGE - 15 V | T _j = 150 °C | | t.b.d. | | mJ |
| R _{th(j-s)} | per Diode, λ _{paste} =0 | .8 W/(mK) | | | | K/W |
| R _{th(j-s)} | per Diode, λ _{paste} =2 | .5 W/(mK) | | | | K/W |
| Diode 7 - | 12 | | | | | |
| $V_F = V_{EC}$ | I _F = 25 A | T _j = 25 °C | | 2.41 | 2.74 | V |
| | V _{GE} = 0 V chiplevel | T _j = 150 °C | | 2.45 | 2.79 | V |
| V_{F0} | chiplevel | T _j = 25 °C | | 1.30 | 1.50 | V |
| | Criipievei | T _j = 150 °C | | 0.90 | 1.10 | V |
| r _F | chiplevel | T _j = 25 °C | | 44 | 50 | mΩ |
| | Chipievei | T _j = 150 °C | | 62 | 68 | mΩ |
| I _{RRM} | $I_F = 25 \text{ A}$ | T _j = 150 °C | | 23 | | Α |
| Q _{rr} | $di/dt_{off} = 732 \text{ A/}\mu\text{s}$ $V_{GE} = -15 \text{ V}$ | T _j = 150 °C | | 3.8 | | μC |
| E _{rr} | V _{CC} = 600 V | T _j = 150 °C | | 1.4 | | mJ |
| R _{th(j-s)} | per Diode, λ _{paste} =0 | .8 W/(mK) | | 1.6 | | K/W |
| R _{th(j-s)} | per Diode, λ _{paste} =2 | .5 W/(mK) | | 1.37 | | K/W |
| Module | | | | | | |
| L _{CE} | | | | - | | nΗ |
| Ms | to heat sink | | 2 | | 2.5 | Nm |
| W | | | | 55 | | g |
| Temperat | ure Sensor | | | | | |
| R ₁₀₀ | T _r =100°C (R ₂₅ =100 | | 1670 ± 3% | | Ω | |
| R _(T) | $R_{(T)}$ =1000 Ω [1+A(T, A = 7.635*10 ⁻³ °C-B = 1.731*10 ⁻⁵ °C-2 | -25°C)+B(T-25°C) ²] -1 °C ⁻¹ , °C ⁻² | | | | |

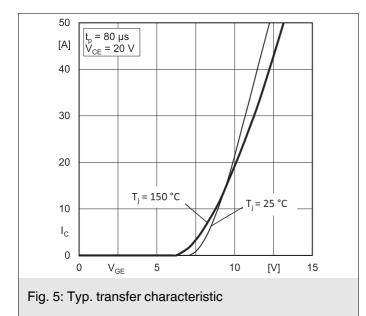


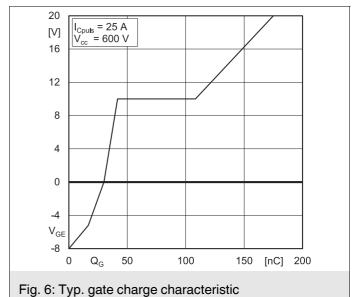


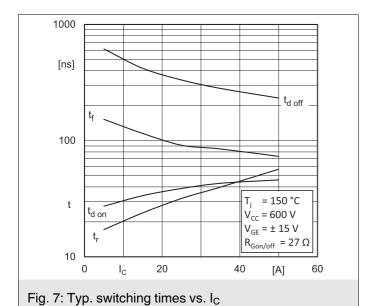


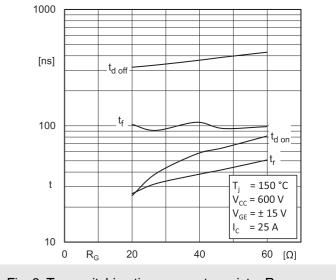














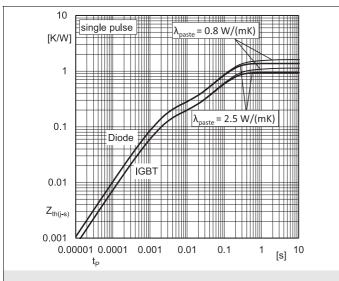


Fig. 9: Typ. transient thermal impedance

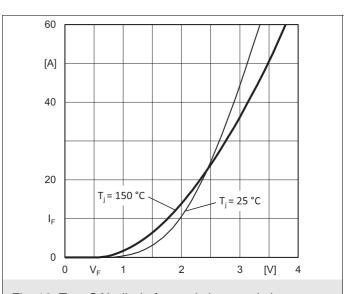


Fig. 10: Typ. CAL diode forward characteristic

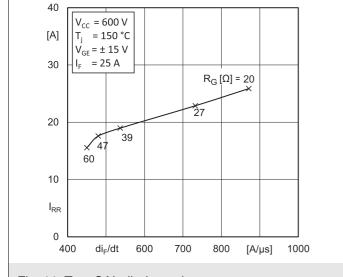


Fig. 11: Typ. CAL diode peak reverse recovery current

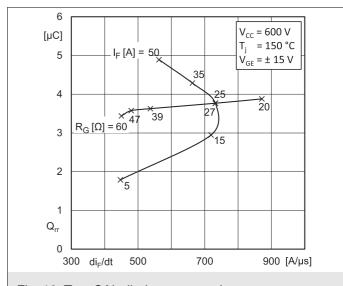
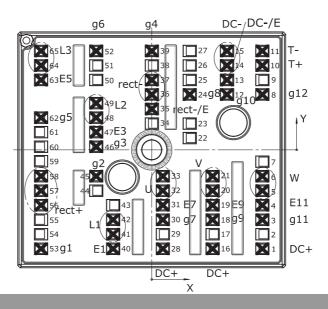


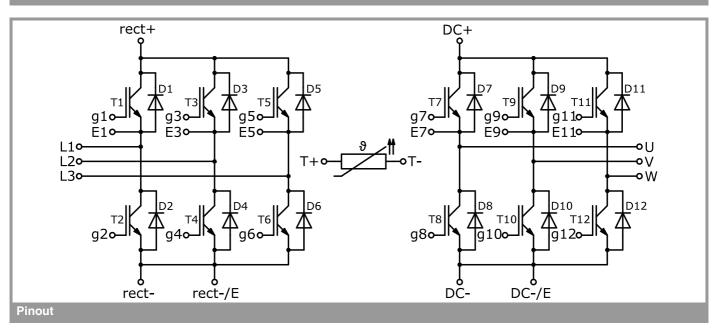
Fig. 12: Typ. CAL diode recovery charge

| Pin out | | | | | | | | | | | |
|---------|-------|--------|----------|-----|--------|--------|----------|-----|--------|--------|----------|
| Pin | Χ | Y | Function | Pin | Χ | Υ | Function | Pin | Χ | Y | Function |
| 1 | 24,38 | -21,80 | DC+ | 23 | 8,38 | 5,80 | | 45 | -12,23 | -5,80 | g2 |
| 2 | 24,38 | -18,60 | | 24 | 8,38 | 12,20 | g8 | 46 | -12,23 | 0,70 | g3 |
| 3 | 24,38 | -15,40 | g11 | 25 | 8,38 | 15,40 | | 47 | -12,23 | 3,90 | E3 |
| 4 | 24,38 | -12,20 | E11 | 26 | 8,38 | 18,60 | | 48 | -12,23 | 7,10 | L2 |
| 5 | 24,38 | -9,00 | W | 27 | 8,38 | 21,80 | | 49 | -12,23 | 10,30 | L2 |
| 6 | 24,38 | | W | 28 | 2,46 | -21,80 | DC+ | 50 | -12,23 | 15,40 | |
| 7 | 24,38 | | | 29 | 2,46 | -18,60 | | 51 | -12,23 | 18,60 | |
| 8 | 24,38 | | g12 | 30 | 2,46 | -15,40 | | 52 | -12,23 | | |
| 9 | 24,38 | 15,40 | | 31 | 2,46 | -12,20 | E7 | 53 | -24,38 | -21,80 | g1 |
| 10 | 24,38 | 18,60 | T+ | 32 | 2,46 | -9,00 | U | 54 | -24,38 | -18,60 | |
| 11 | 24,38 | | T- | 33 | 2,46 | -5,80 | U | 55 | -24,38 | | |
| 12 | 16,58 | 12,20 | g10 | 34 | 0,03 | 5,80 | | 56 | -24,38 | | rect+ |
| 13 | 16,58 | 15,40 | DC-/E | 35 | 0,03 | 9,00 | rect-/E | 57 | -24,38 | -9,00 | rect+ |
| 14 | 16,58 | 18,60 | DC- | 36 | 0,03 | 12,20 | rect- | 58 | -24,38 | -5,80 | rect+ |
| 15 | 16,58 | 21,80 | DC- | 37 | 0,03 | 15,40 | rect- | 59 | -24,38 | -2,50 | |
| 16 | 13,42 | -21,80 | DC+ | 38 | 0,03 | 18,60 | | 60 | -24,38 | 0,70 | |
| 17 | 13,42 | -18,60 | | 39 | 0,03 | 21,80 | | 61 | -24,38 | | |
| 18 | 13,42 | -15,40 | g9 | 40 | -8,51 | -21,80 | E1 | 62 | -24,38 | 7,10 | g5 |
| 19 | 13,42 | -12,20 | E9 | 41 | -8,51 | -18,60 | L1 | 63 | -24,38 | 15,40 | E5 |
| 20 | 13,42 | -9,00 | V | 42 | -8,51 | -15,40 | L1 | 64 | -24,38 | 18,60 | L3 |
| 21 | 13,42 | -5,80 | V | 43 | -8,51 | -12,20 | | 65 | -24,38 | 21,80 | L3 |
| 22 | 8,38 | 2,60 | | 44 | -12,23 | -9,00 | | | | | |

all values in mm



Pinout and Dimensions



This is an electrostatic discharge sensitive device (ESDS) due to international standard IEC 61340.

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